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## a) Learning Pod

```
% POD members: Meghan, Raymond
% Struggle: I had difficulty finding a way to implement refractory period,
% I did not know how to check for refractory period in the for loop
% Help from POD: We discussed the logic to implement refractory period in
% the POD, we wrote the pseudocode to try to make our logic clear. I was
% able to implement the refractory period with the help from my POD.
```

## b) Compare and contrast the modifications to the ALIF model

```
% Differences in mechanisms:
% The LIF model is one of the simplest forms of a neuron model that
% includes a membrane potential that leaks over time towards a baseline
% or rest potential, influenced by a linear resistance and capacitance.
% When the membrane potential reaches a threshold, the neuron fires
% (generates a spike), and the membrane potential is reset to a lower
% value.
% The AELIF model extends the LIF model by introducing an adaptation
% mechanism through an additional current termed I_SRA (Spike Rate
% Adaptation). This current increases following a spike and decays
% exponentially, affecting the neuron's excitability. It also includes an
% exponential term that makes the model more biologically realistic,
% allowing it to better capture the sharp upswing of action potentials
% observed in real neurons.
```

```
% Difference in terms and equations:
% LIF:  $C_m \frac{dV_m}{dt} = \frac{(E_L - V_m)}{R_m} + I_{app}$ 
% V is the membrane potential
% E_L is the leak potential
% R_m is the membrane resistance
% C_m is the membrane capacitance
% I_{app} is the applied current
```

```
% AELIF:
```

---

```
%  $C_m \frac{dV_m}{dt} = G_L \left[ E_L - V_m + \Delta_{th} \exp \left( \frac{V_m - V_{th}}{\Delta_{th}} \right) \right] - I_{SRA} + I_{app}$ 
%  $\Delta_{th}$  introduces an exponential component to the spike mechanism
%  $G_L$  is the leak conductance
%  $I_{SRA}$  is the adaptation current
```

```
% Difference in model behavior changes
% LIF: The response of the LIF model to constant input currents is
% relatively linear and predictable, without accommodation or adaptation
% over time. The spike frequency is directly related to the input current
% without any form of frequency adaptation.
% The AELIF model shows adaptation to prolonged stimuli. After an initial
% response to a sustained input current, the firing rate decreases over
% time due to the increasing adaptation current. Exhibits more complex
% behaviors like bursting and adaptation, which are closer to biological
% neuron behaviors. The exponential term allows the neuron to respond more
% aggressively as the potential approaches the threshold.
```

```
% In summary, the AELIF model incorporates additional complexity and
% biological realism into the basic LIF framework, allowing it to simulate
% more sophisticated behaviors observed in real neurons, such as adaptation
% and the sharp spike upswing. These enhancements make the AELIF model
% suitable for more detailed studies of neuronal behavior under various
% input conditions, providing insights into the dynamics of adaptation
% and firing patterns in response to different stimuli.
```

## c) Tutorial 2.2 Q1

```
function [V, spike_times] = simulate_neuron_Q1(I_app, t, E_L, G_L, C_m, V_th,
V_reset, delta_t, tau_ref, V_peak)
    V = zeros(length(I_app), length(t)); % Initialize membrane potential
matrix
    spike_times = cell(length(I_app), 1); % Use a cell array to store spike
times for each I_app

    for i = 1:length(I_app)
        last_spike_time = -inf; % Initialize the last spike time
        V(i,1) = E_L; % Set the initial condition for each simulation

        for k = 2:length(t)
            % Check for refractory period
            if (t(k) > last_spike_time + tau_ref)
                dVdt = G_L * (E_L - V(i, k-1)) + I_app(i);
                V(i, k) = V(i, k-1) + dVdt * (delta_t / C_m);
            else
                V(i, k) = V_reset;
            end

            % Check for spikes
            if (V(i, k) >= V_th)
                V(i, k) = V_peak; % Set to V_peak for visualization
            end
        end
    end
end
```

---

```

        last_spike_time = t(k); % Update last spike time
        spike_times{i} = [spike_times{i}, t(k)]; % Record spike time
    end
end
end

% Parameters
E_L = -70e-3;      % Leak potential in volts
R_m = 100e6;       % Membrane resistance in ohms
G_L = 1 / R_m;     % Conductance in Siemens
C_m = 0.1e-9;      % Membrane capacitance in farads
V_th = -50e-3;     % Spike threshold in volts
V_reset = -65e-3;  % Reset potential in volts
V_peak = 50e-3;    % Spike peak in volts
tau_ref = 2.5e-3;  % Refractory period in seconds

% Create time vector
delta_t = 0.1e-3; % Time step in seconds (0.1 ms)
tmax = 2;         % Maximum time in seconds
t = 0:delta_t:tmax; % Time vector from 0 to tmax with steps of delta_t

% Input currents
I_app = [220e-12, 600e-12]; % Example input currents

% Call the simulate_neuron_Q1 function
[V_Q1, spike_times_Q1] = simulate_neuron_Q1(I_app, t, E_L, G_L, C_m, V_th,
V_reset, delta_t, tau_ref, V_peak);

% Initialize the results arrays for Q1
mean_firing_rates_Q1 = zeros(size(I_app));
mean_membrane_potentials_Q1 = zeros(size(I_app));

% Data Analysis for Q1
for i = 1:length(I_app)
    % Calculate the mean firing rate
    mean_firing_rates_Q1(i) = length(spike_times_Q1{i}) / tmax; % Firing rate
in Hz

    % Calculate the mean membrane potential excluding the time of spikes
    % Here we use V_peak to exclude spike peaks for calculation
    mean_membrane_potentials_Q1(i) = mean(V_Q1(i, V_Q1(i,:) < V_peak));
end

% Plotting for Q1

% Plot mean firing rate as a function of input current for Q1
figure;
plot(I_app * 1e12, mean_firing_rates_Q1, 'r-o'); % Convert A to pA for the
x-axis
xlabel('Input Current (pA)');
ylabel('Mean Firing Rate (Hz)');
title('Q1: Mean Firing Rate vs Input Current');

```

---

---

```

legend('Q1 Firing Rate');

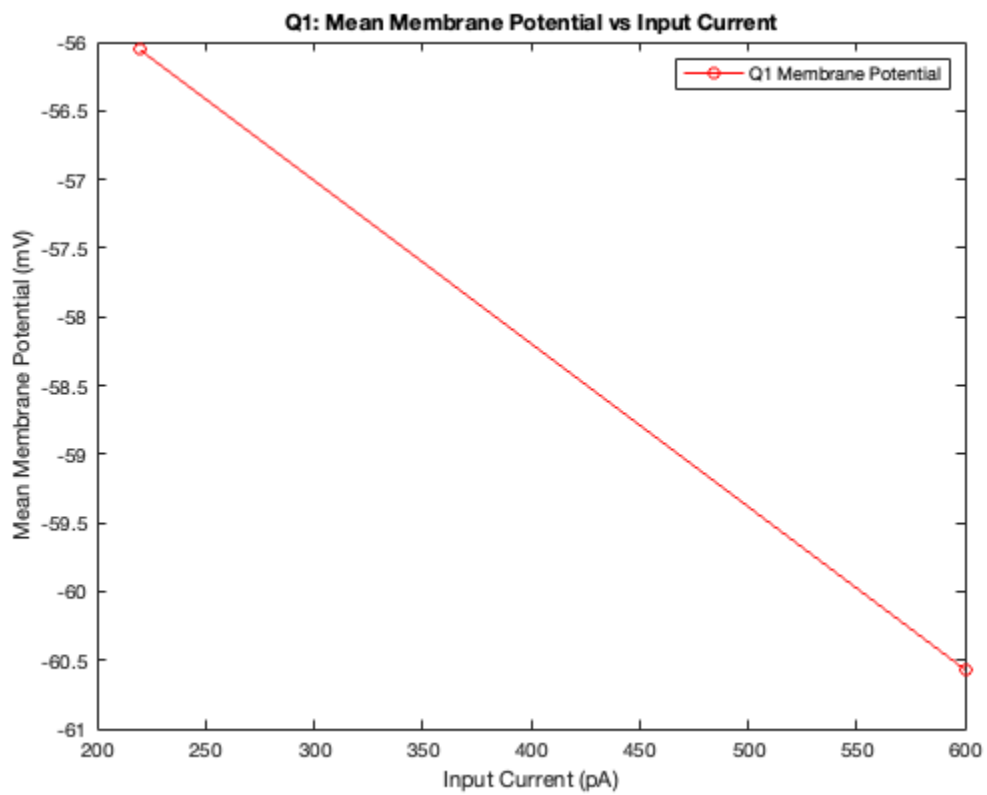
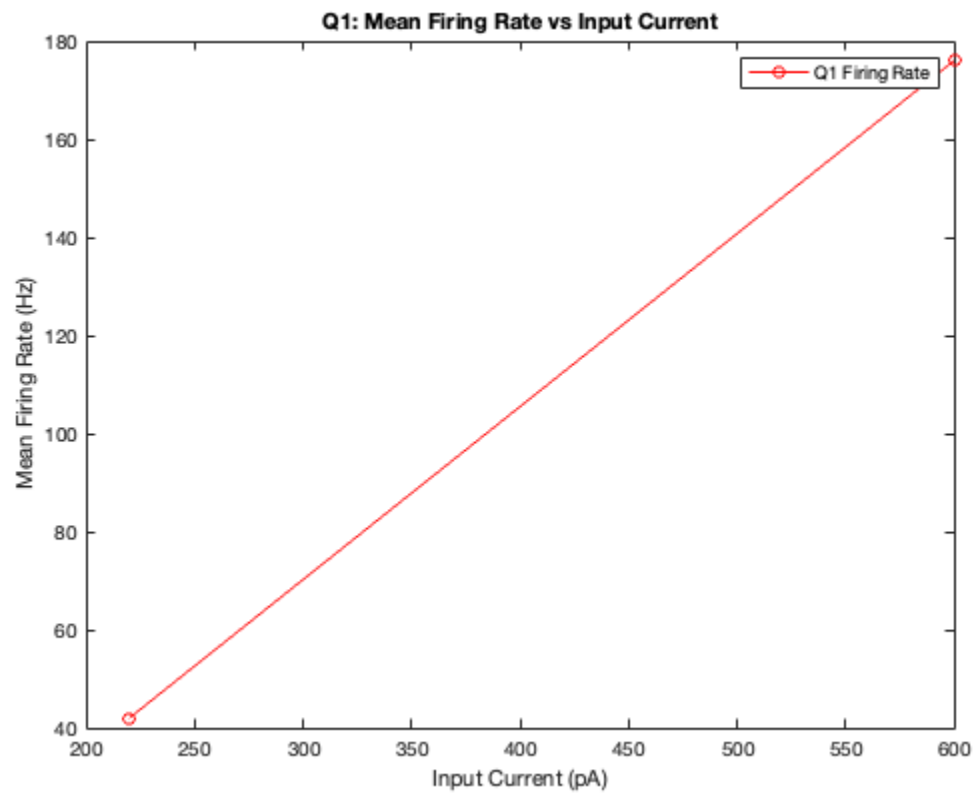
% Plot mean membrane potential as a function of input current for Q1
figure;
plot(I_app * 1e12, mean_membrane_potentials_Q1 * 1e3, 'r-o'); % Convert V to
mV for the y-axis
xlabel('Input Current (pA)');
ylabel('Mean Membrane Potential (mV)');
title('Q1: Mean Membrane Potential vs Input Current');
legend('Q1 Membrane Potential');

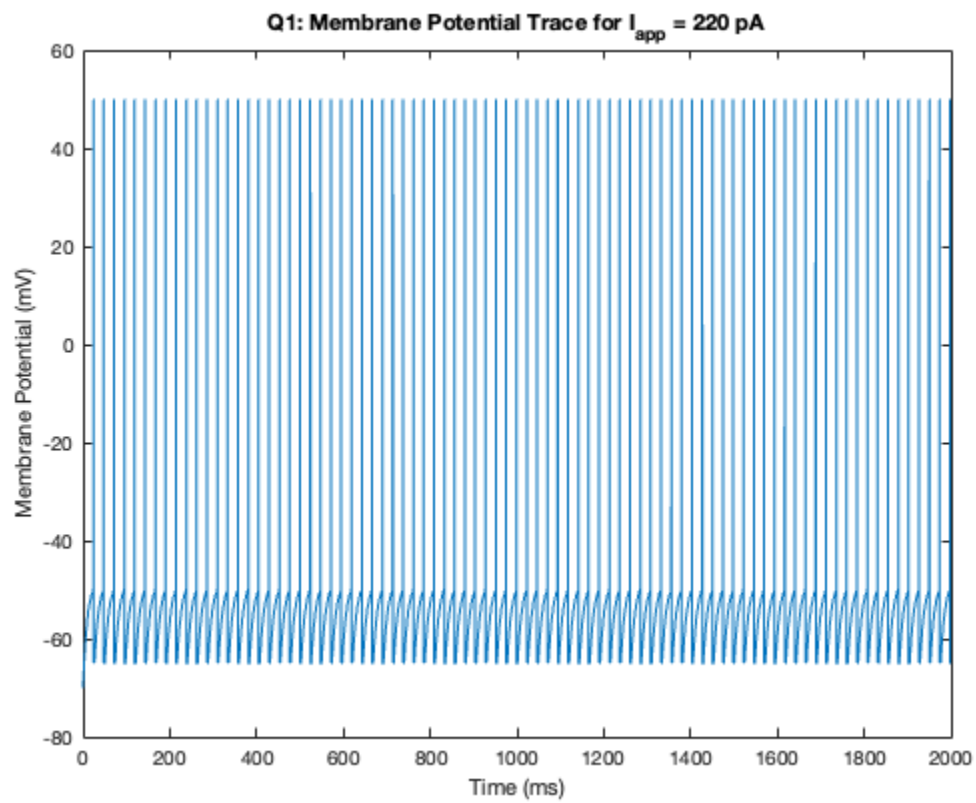
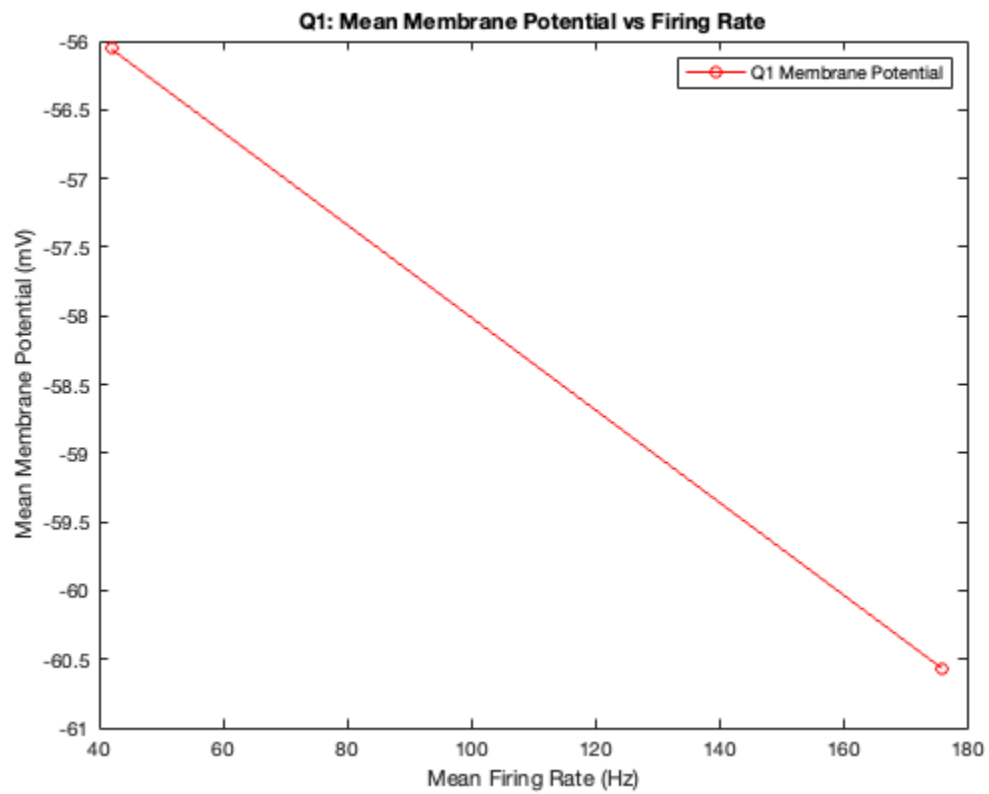
% Plot mean membrane potential as a function of firing rate for Q1
figure;
plot(mean_firing_rates_Q1, mean_membrane_potentials_Q1 * 1e3, 'r-o'); %
Convert V to mV for the y-axis
xlabel('Mean Firing Rate (Hz)');
ylabel('Mean Membrane Potential (mV)');
title('Q1: Mean Membrane Potential vs Firing Rate');
legend('Q1 Membrane Potential');

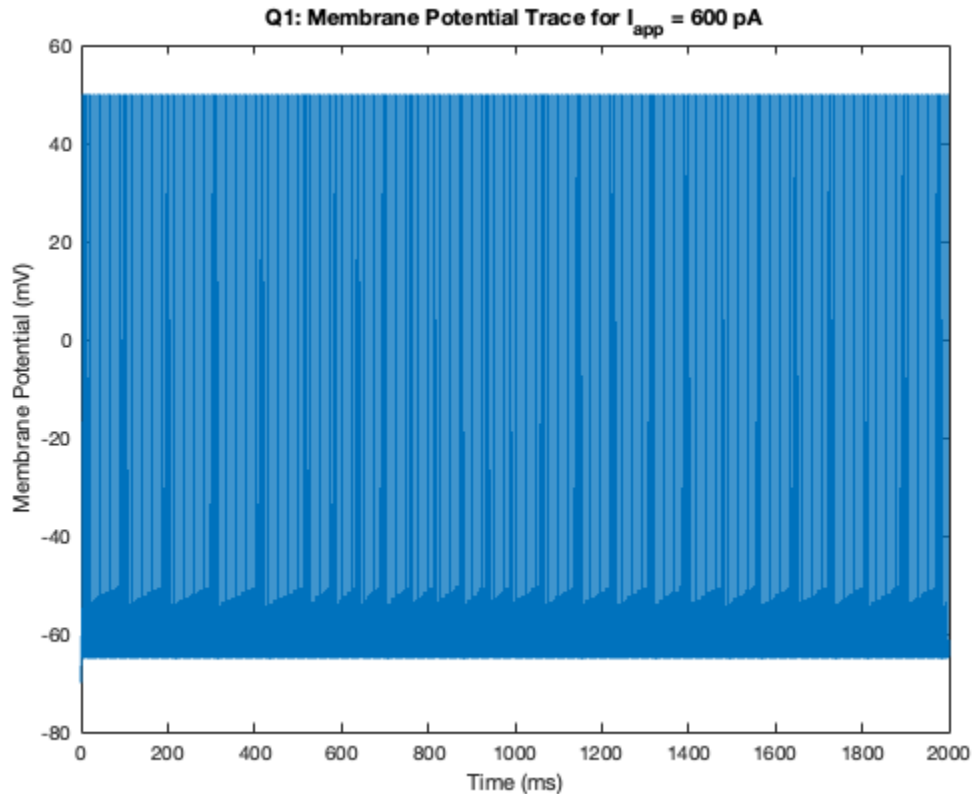
% Additionally, plot the membrane potential over time for specific I_app
values for Q1
% Identify the indices for I_app = 220 pA and 600 pA if they are part of your
simulations
indices_of_interest = find(ismember(I_app, [220e-12, 600e-12]));
for i = indices_of_interest
    figure;
    plot(t * 1e3, V_Q1(i,:) * 1e3); % Convert seconds to ms for x-axis and V
to mV for the y-axis
    hold on;
    xlabel('Time (ms)');
    ylabel('Membrane Potential (mV)');
    title(['Q1: Membrane Potential Trace for I_{app} = ' num2str(I_app(i) *
1e12) ' pA']);
    hold off;
end

```

---







## Tutorial 2.2 Q2

```
function [V_Q2, spike_times_Q2, V_th_Q2] = simulate_neuron_Q2(I_app, t, E_L,
G_L, C_m, V_reset, delta_t, tau_ref, ~, tau_V_th, V_th_baseline, V_th_max)
    V_Q2 = zeros(length(I_app), length(t)); % Initialize membrane potential
matrix for Q2
    V_th_Q2 = V_th_baseline * ones(length(I_app), length(t)); % Initialize
dynamic threshold matrix
    spike_times_Q2 = cell(length(I_app), 1); % Use a cell array to store
spike times for each I_app

    for i = 1:length(I_app)
        last_spike_time_Q2 = -inf; % Initialize the last spike time for Q2
        V_Q2(i,1) = E_L; % Set the initial condition for V for each simulation
        V_th_Q2(i,1) = V_th_baseline; % Set the initial condition for V_th
        for each simulation

            for k = 2:length(t)
                % Update V_m(t) if we're past the refractory period
                if (t(k) > last_spike_time_Q2 + tau_ref)
                    dVdt_Q2 = G_L * (E_L - V_Q2(i, k-1)) + I_app(i);
                    V_Q2(i, k) = V_Q2(i, k-1) + dVdt_Q2 * (delta_t / C_m);
                else
                    V_Q2(i, k) = V_reset;
                end
            end
        end
    end
end
```

---

```

    % Update V_th(t)
    dV_th_dt_Q2 = (V_th_baseline - V_th_Q2(i, k-1)) / tau_V_th;
    V_th_Q2(i, k) = V_th_Q2(i, k-1) + dV_th_dt_Q2 * delta_t;

    % Check for spikes
    if (V_Q2(i, k) >= V_th_Q2(i, k))
        V_Q2(i, k) = V_reset; % Reset membrane potential
        V_th_Q2(i, k) = V_th_max; % Increase threshold
        last_spike_time_Q2 = t(k); % Update last spike time for Q2
        spike_times_Q2{i} = [spike_times_Q2{i}, t(k)]; % Record spike
time
    end
end
end

% Parameters for Q2
V_th_baseline_Q2 = -50e-3; % Baseline threshold in volts for Q2
V_th_max_Q2 = 200e-3; % Maximum threshold after spike in volts for Q2
tau_V_th_Q2 = 1e-3; % Time constant for threshold decay in seconds for
Q2

% Call the simulate_neuron_Q2 function
[V_Q2, spike_times_Q2, V_th_Q2] = simulate_neuron_Q2(I_app, t, E_L, G_L,
C_m, V_reset, delta_t, tau_ref, V_peak, tau_V_th_Q2, V_th_baseline_Q2,
V_th_max_Q2);

% Data analysis for Q2
mean_firing_rates_Q2 = zeros(size(I_app));
mean_membrane_potentials_Q2 = zeros(size(I_app));

% Compute mean firing rates and membrane potentials
for i = 1:length(I_app)
    mean_firing_rates_Q2(i) = length(spike_times_Q2{i}) / tmax; % Firing
rate in Hz
    mean_membrane_potentials_Q2(i) = mean(V_Q2(i, V_Q2(i,:) < V_th_max_Q2));
% Exclude spike peaks
end

% Plotting for Q2

% Plot mean firing rate as a function of input current for Q2
figure;
plot(I_app * 1e12, mean_firing_rates_Q2, 'b-o'); % Convert current to pA for
the x-axis
xlabel('Input Current (pA)');
ylabel('Mean Firing Rate (Hz)');
title('Q2: Mean Firing Rate vs Input Current');
legend('Q2 Firing Rate');

% Plot mean membrane potential as a function of input current for Q2
figure;
plot(I_app * 1e12, mean_membrane_potentials_Q2 * 1e3, 'b-o'); % Convert V to

```

---



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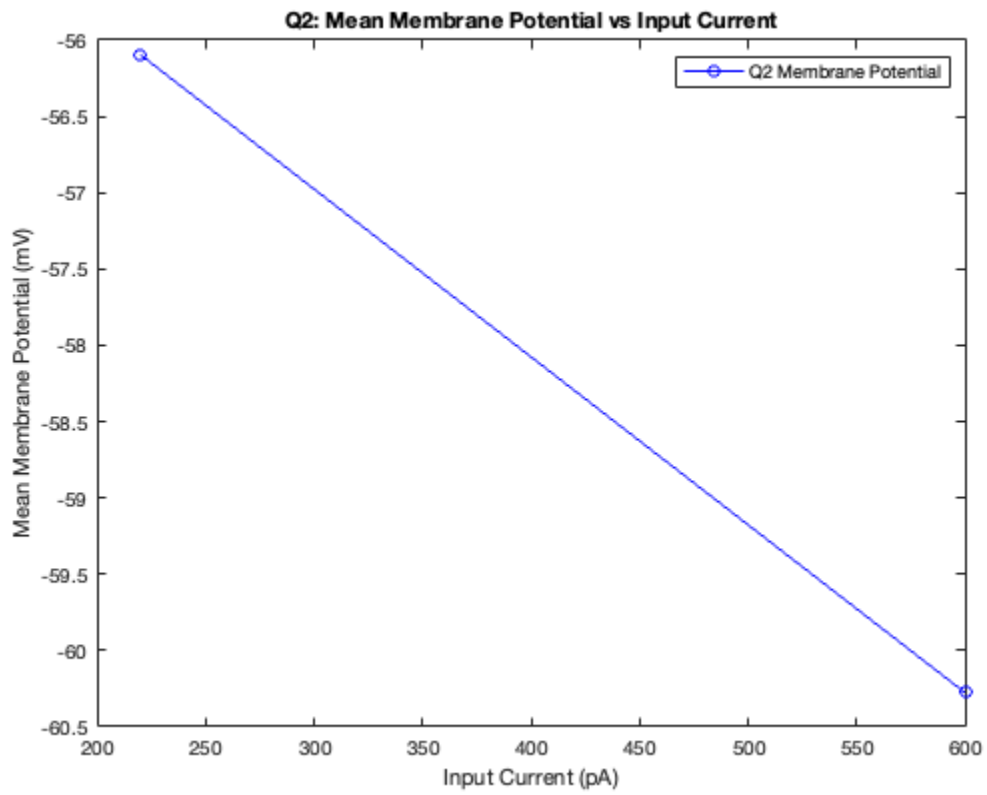
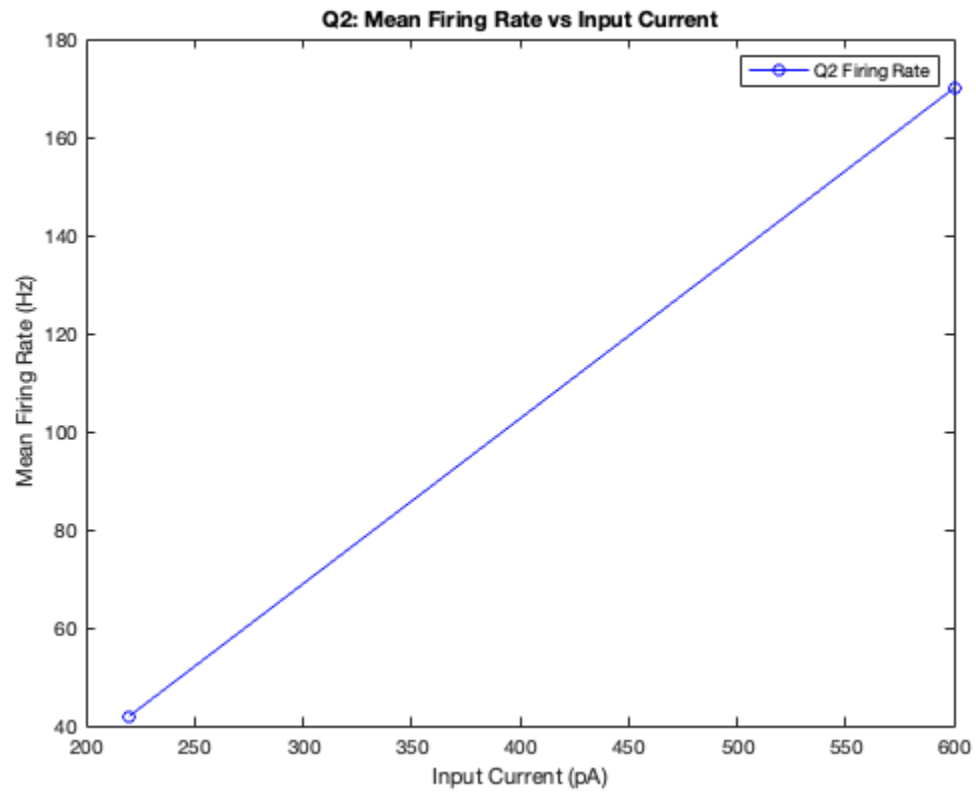
```

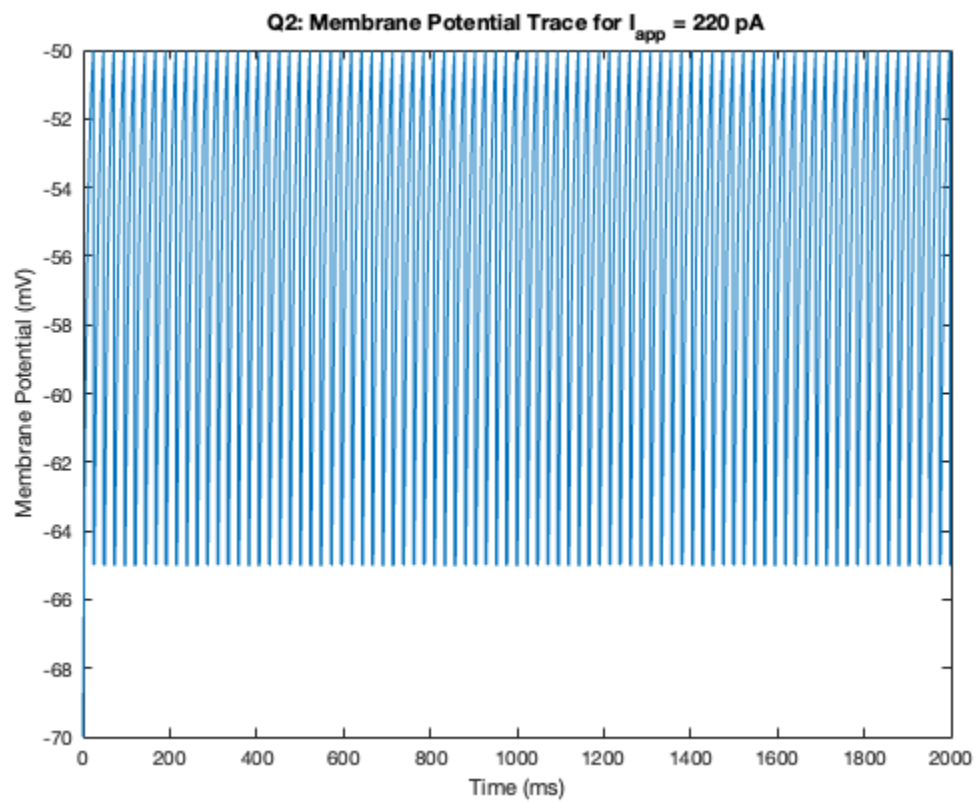
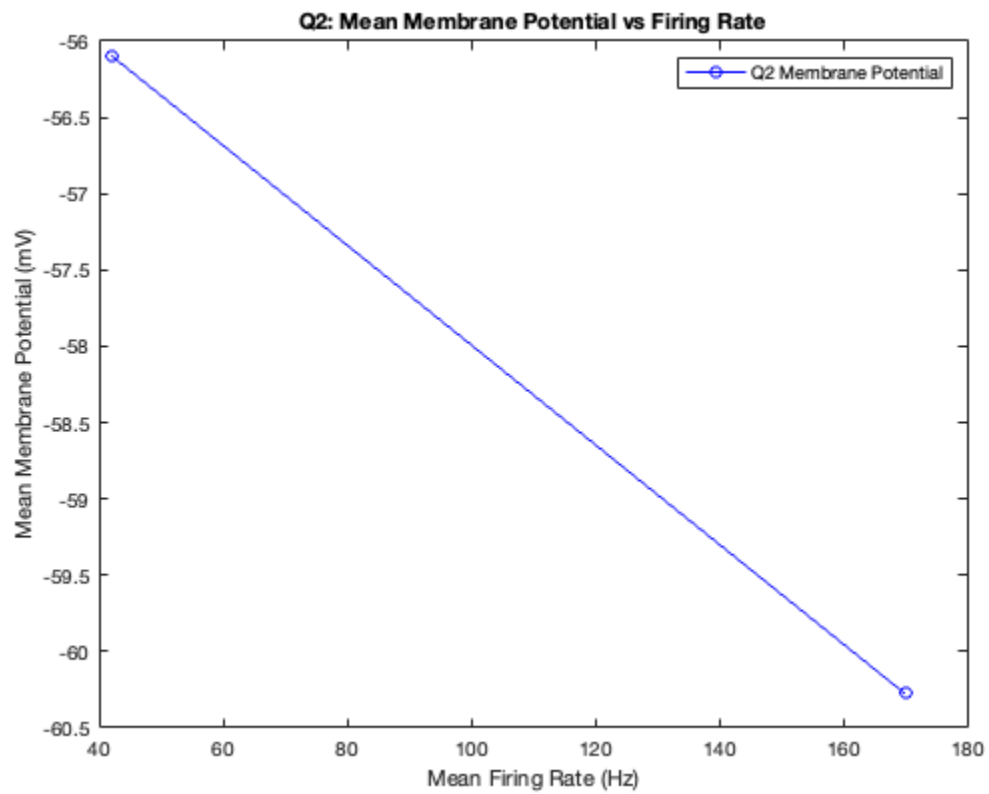
mV for the y-axis
xlabel('Input Current (pA)');
ylabel('Mean Membrane Potential (mV)');
title('Q2: Mean Membrane Potential vs Input Current');
legend('Q2 Membrane Potential');

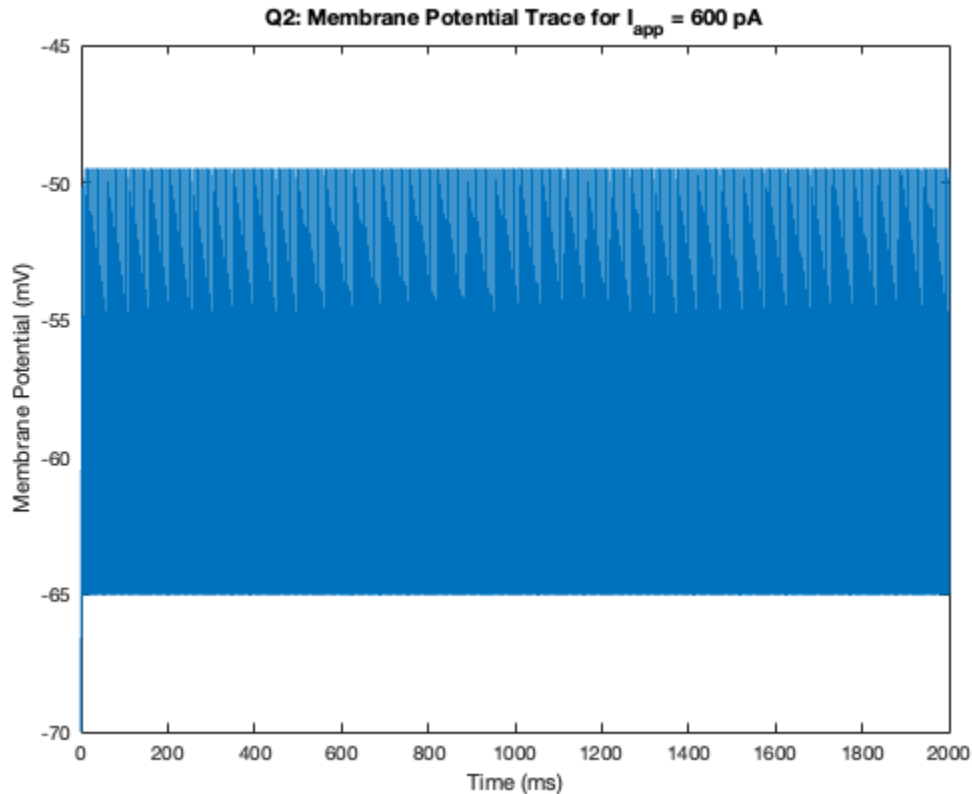
% Plot mean membrane potential as a function of firing rate for Q2
figure;
plot(mean_firing_rates_Q2, mean_membrane_potentials_Q2 * 1e3, 'b-o'); %
Convert V to mV for the y-axis
xlabel('Mean Firing Rate (Hz)');
ylabel('Mean Membrane Potential (mV)');
title('Q2: Mean Membrane Potential vs Firing Rate');
legend('Q2 Membrane Potential');

% Additionally, plot the membrane potential as a function of time for
specific I_app values
% (e.g., 220 pA and 600 pA, but you need to find their indices in the I_app
array)
for i = 1:length(I_app)
    figure;
    plot(t * 1e3, V_Q2(i,:) * 1e3); % Convert seconds to ms for the x-axis
    and V to mV for the y-axis
    hold on;
    xlabel('Time (ms)');
    ylabel('Membrane Potential (mV)');
    title(['Q2: Membrane Potential Trace for I_{app} = ' num2str(I_app(i) *
1e12) ' pA']);
    hold off;
end

```







## Tutorial 2.2 Q3

```
function [V, spike_times, V_th, G_ref] = simulate_neuron_Q3(I_app, t, E_L,
G_L, C_m, V_reset, delta_t, tau_ref, ~, tau_V_th, V_th_baseline, V_th_max,
E_K, tau_G_ref, Delta_G)
    V = zeros(length(I_app), length(t)); % Initialize membrane potential
matrix
    V_th = V_th_baseline * ones(length(I_app), length(t)); % Initialize
dynamic threshold matrix
    G_ref = zeros(length(I_app), length(t)); % Initialize refractory
conductance matrix
    spike_times = cell(length(I_app), 1); % Use a cell array to store spike
times for each I_app

    for i = 1:length(I_app)
        last_spike_time = -inf; % Initialize the last spike time
        V(i,1) = E_L; % Set the initial condition for each simulation
        V_th(i,1) = V_th_baseline; % Set the initial condition for V_th for
each simulation

        for k = 2:length(t)
            % Update V_m(t) if we're past the refractory period
            if (t(k) > last_spike_time + tau_ref)
                dVdt = G_L * (E_L - V(i, k-1)) + G_ref(i, k-1) * (E_K - V(i,
k-1)) + I_app(i);
```

---

```

        V(i, k) = V(i, k-1) + dVdt * (delta_t / C_m);
    else
        V(i, k) = V_reset;
    end

    % Update G_ref(t)
    dG_ref_dt = -G_ref(i, k-1) / tau_G_ref;
    G_ref(i, k) = G_ref(i, k-1) + dG_ref_dt * delta_t;

    % Update V_th(t)
    dV_th_dt = (V_th_baseline - V_th(i, k-1)) / tau_V_th;
    V_th(i, k) = V_th(i, k-1) + dV_th_dt * delta_t;

    % Check for spikes
    if (V(i, k) >= V_th(i, k))
        V(i, k) = V_reset; % Reset membrane potential
        V_th(i, k) = V_th_max; % Increase threshold
        G_ref(i, k) = G_ref(i, k) + Delta_G; % Increase refractory
conductance
        last_spike_time = t(k); % Update last spike time
        spike_times{i} = [spike_times{i}, t(k)]; % Record spike time
    end
end
end
end

% Additional parameters specific to Q3
E_K = -80e-3; % Potassium reversal potential in volts
tau_G_ref = 0.2e-3; % Time constant for G_ref decay in seconds
Delta_G = 2e-6; % Increment in refractory conductance in Siemens (2 micro
Siemens)
tau_V_th = 1e-3; % Time constant for the decay of the threshold voltage
V_th_baseline = -50e-3; % Baseline threshold voltage in volts
V_th_max = 200e-3; % Maximum threshold voltage after a spike in volts

% Assume other parameters (like E_L, R_m, C_m, etc.) are already defined in
your script.
% Call the function for Q3
[V_Q3, spike_times_Q3, V_th_Q3, G_ref_Q3] = simulate_neuron_Q3(I_app, t,
E_L, G_L, C_m, V_reset, delta_t, tau_ref, V_peak, tau_V_th, V_th_baseline,
V_th_max, E_K, tau_G_ref, Delta_G);

% Initialize arrays to store results
mean_firing_rates_Q3 = zeros(size(I_app));
mean_membrane_potentials_Q3 = zeros(size(I_app));

% Compute mean firing rates and membrane potentials
for i = 1:length(I_app)
    mean_firing_rates_Q3(i) = length(spike_times_Q3{i}) / tmax; % Firing rate
in Hz
    mean_membrane_potentials_Q3(i) = mean(V_Q3(i, V_Q3(i,:) < V_peak)); %
Exclude spike peaks for calculation
end

```

---

---

```

% Plot mean firing rate as a function of input current for Q3
figure;
plot(I_app * 1e12, mean_firing_rates_Q3, 'g-o'); % Convert A to pA for the
x-axis
xlabel('Input Current (pA)');
ylabel('Mean Firing Rate (Hz)');
title('Q3: Mean Firing Rate vs Input Current');
legend('Q3 Firing Rate');

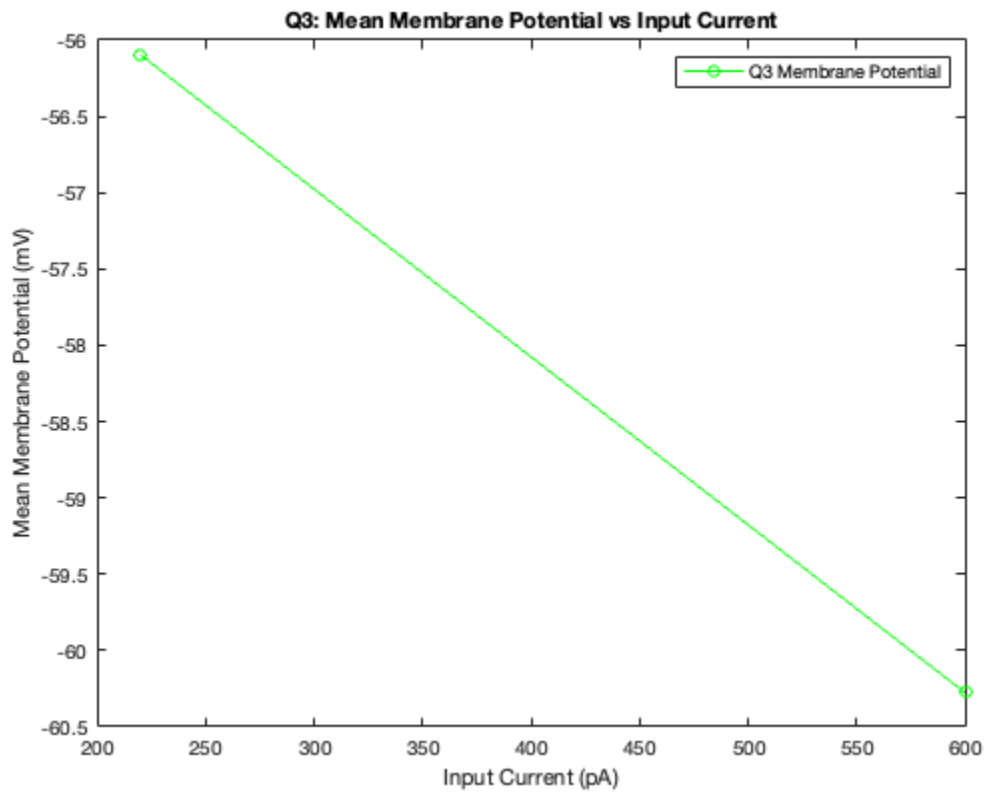
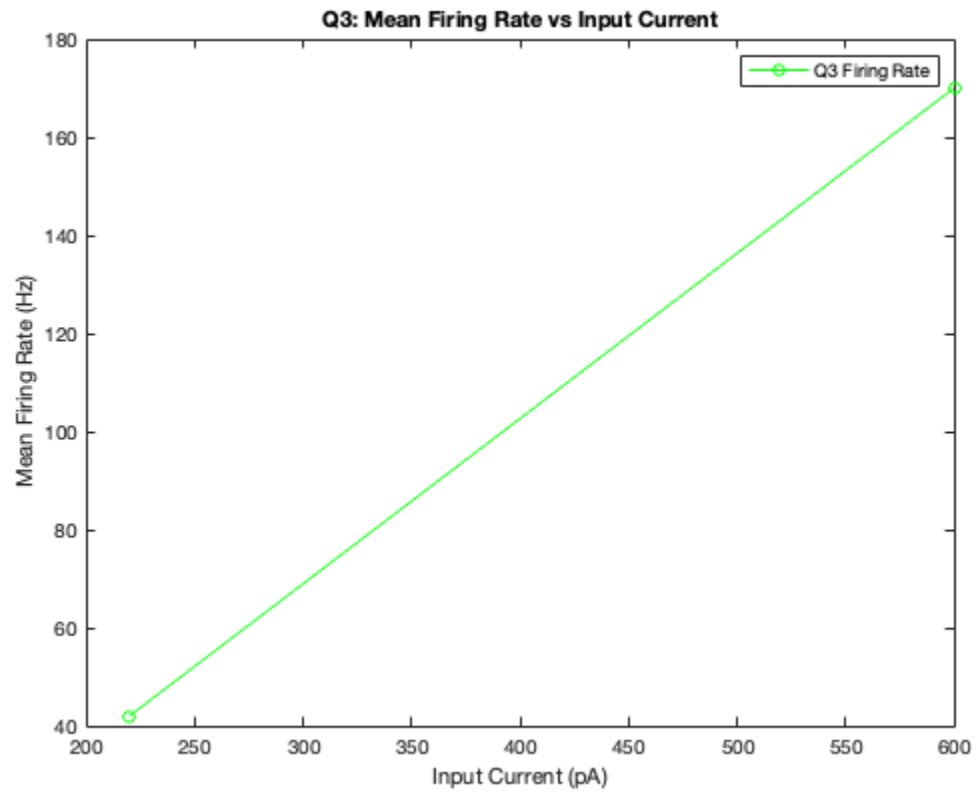
% Plot mean membrane potential as a function of input current for Q3
figure;
plot(I_app * 1e12, mean_membrane_potentials_Q3 * 1e3, 'g-o'); % Convert V to
mV for the y-axis
xlabel('Input Current (pA)');
ylabel('Mean Membrane Potential (mV)');
title('Q3: Mean Membrane Potential vs Input Current');
legend('Q3 Membrane Potential');

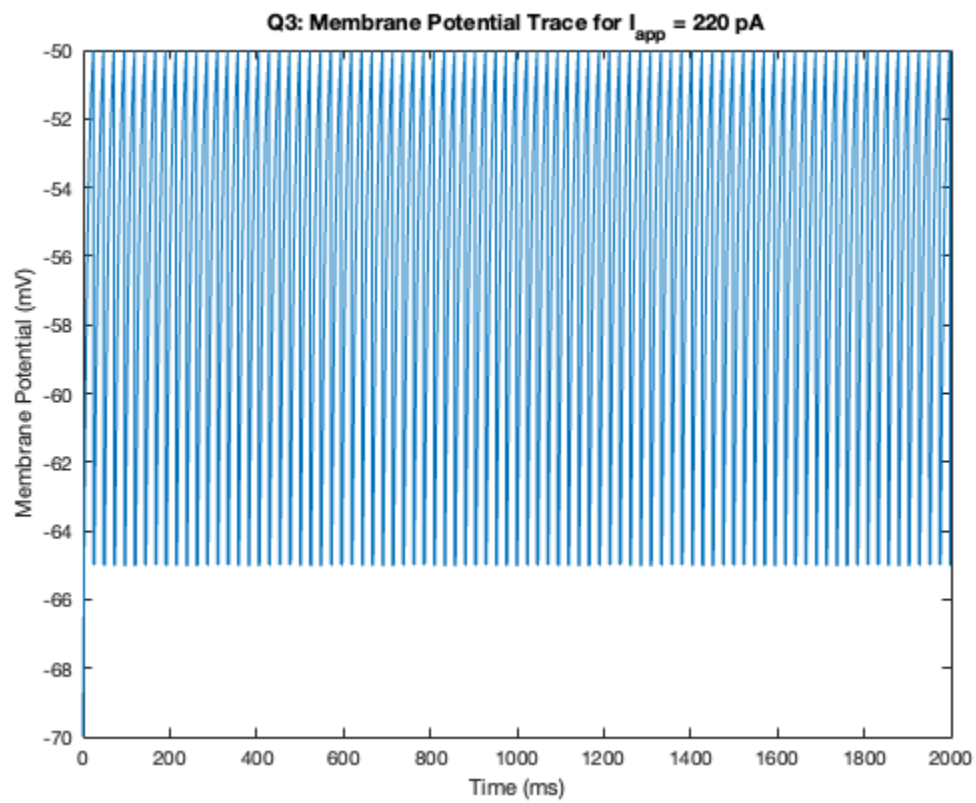
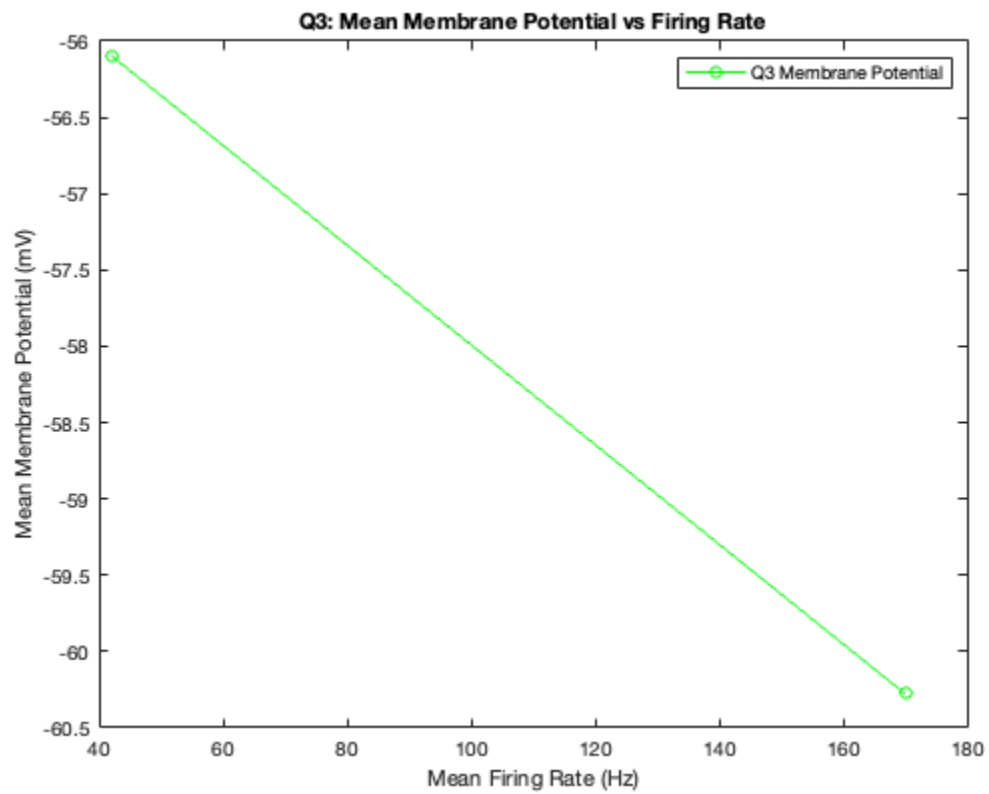
% Plot mean membrane potential as a function of firing rate for Q3
figure;
plot(mean_firing_rates_Q3, mean_membrane_potentials_Q3 * 1e3, 'g-o'); %
Convert V to mV for the y-axis
xlabel('Mean Firing Rate (Hz)');
ylabel('Mean Membrane Potential (mV)');
title('Q3: Mean Membrane Potential vs Firing Rate');
legend('Q3 Membrane Potential');

% Membrane potential traces ver time for specific I_app values for Q3
indices_of_interest = find(ismember(I_app, [220e-12, 600e-12])); % Example
indices
for i = indices_of_interest
    figure;
    plot(t * 1e3, V_Q3(i,:) * 1e3); % Convert seconds to ms for x-axis and V
to mV for the y-axis
    hold on;
    xlabel('Time (ms)');
    ylabel('Membrane Potential (mV)');
    title(['Q3: Membrane Potential Trace for I_{app} = ' num2str(I_app(i) *
1e12) ' pA']);
    hold off;
end

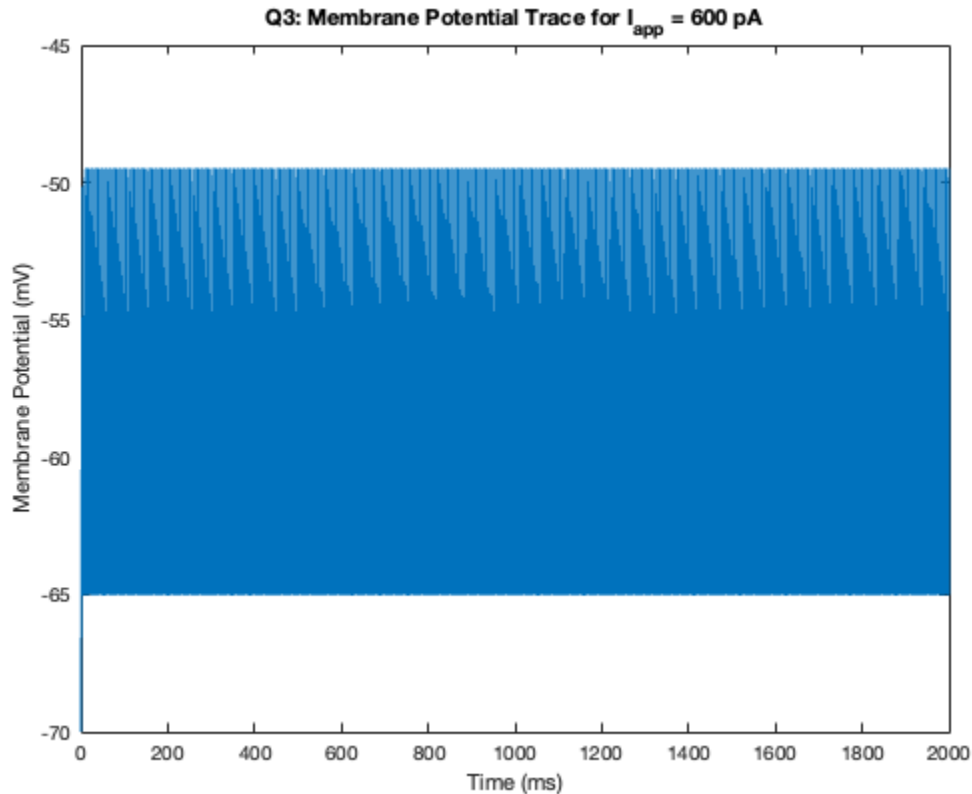
```

---









## Tutorial 2.3 Q1 Part a

```
function [t, V, G_SRA, I_app] = simulate_LIF_with_adaptation(T, dt, I_app,
params)
    % Unpack parameters
    E_L = params.E_L;      % Leak reversal potential
    V_th = params.V_th;    % Spike threshold
    V_reset = params.V_reset; % Reset potential
    R_m = params.R_m;      % Membrane resistance
    C_m = params.C_m;      % Membrane capacitance
    E_K = params.E_K;      % Potassium reversal potential
    Delta_G_SRA = params.Delta_G_SRA; % Change in G_SRA at spike
    tau_SRA = params.tau_SRA; % Time constant for SRA decay

    % Time vector
    t = 0:dt:T;

    % Initialize variables
    V = E_L * ones(size(t)); % Membrane potential
    G_SRA = zeros(size(t)); % Spike Rate Adaptation conductance

    % Simulation loop
    for i = 2:length(t)
        % Update the membrane potential
        dVdt = (E_L - V(i-1)) / R_m + G_SRA(i-1) * (E_K - V(i-1)) +
```

---

```

I_app(i) / C_m;
    V(i) = V(i-1) + dt * dVdt;

    % Update the adaptation conductance
    dG_SRA_dt = -G_SRA(i-1) / tau_SRA;
    G_SRA(i) = G_SRA(i-1) + dt * dG_SRA_dt;

    % Spike event
    if V(i) >= V_th
        V(i) = V_reset;
        G_SRA(i) = G_SRA(i) + Delta_G_SRA;
    end
end
end

% Parameters
params = struct();
params.E_L = -75e-3;           % Leak reversal potential in volts
params.V_th = -50e-3;         % Spike threshold in volts
params.V_reset = -80e-3;      % Reset potential in volts
params.R_m = 100e6;           % Membrane resistance in ohms
params.C_m = 100e-12;         % Membrane capacitance in farads
params.E_K = -80e-3;          % Potassium reversal potential in volts
params.Delta_G_SRA = 1e-9;    % Change in G_SRA at spike in Siemens
params.tau_SRA = 200e-3;      % Time constant for SRA decay in seconds

% Simulation settings
T = 1.5;                       % Total time in seconds
dt = 1e-4;                     % Time step in seconds
t = 0:dt:T;                    % Time vector
I_app = zeros(size(t)) + 500e-12; % Current in amperes
I_app(t < 0.5 | t > 1.0) = 0; % Current pulse from 0.5 s to 1.0 s

% Run the simulation
[t, V, G_SRA, I_app] = simulate_LIF_with_adaptation(T, dt, I_app, params);

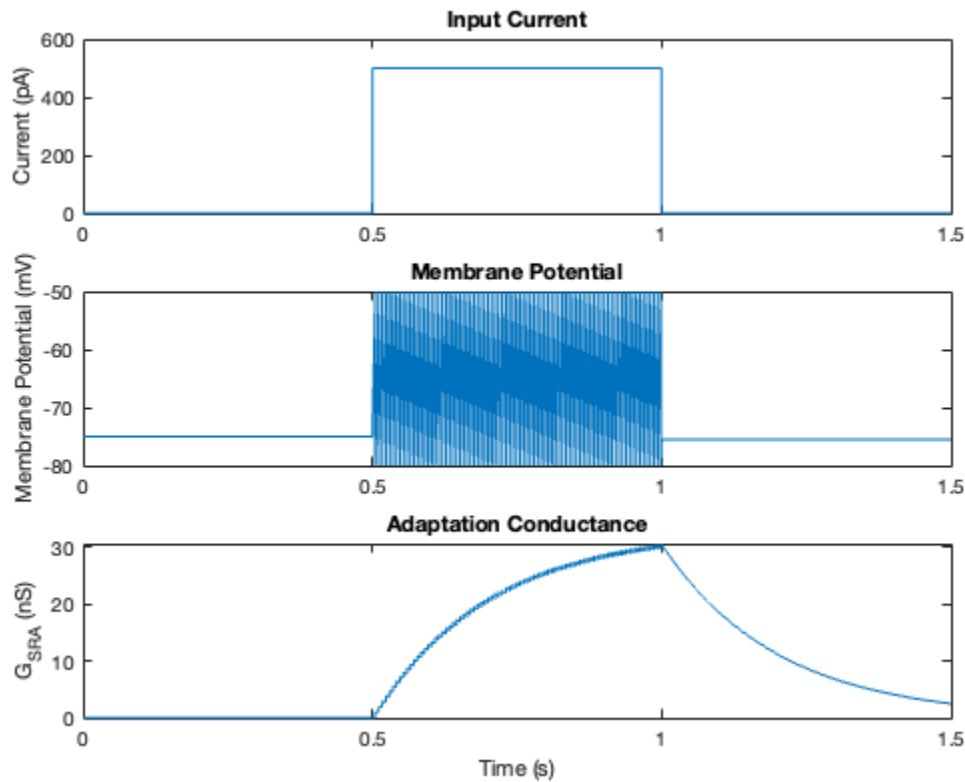
% Plotting
figure;
subplot(3,1,1);
plot(t, I_app * 1e12);
ylabel('Current (pA)');
title('Input Current');

subplot(3,1,2);
plot(t, V * 1e3);
ylabel('Membrane Potential (mV)');
title('Membrane Potential');

subplot(3,1,3);
plot(t, G_SRA * 1e9);
ylabel('G_{SRA} (nS)');
xlabel('Time (s)');
title('Adaptation Conductance');

```

---



## Tutorial 2.3 Q1 Part b

```
% Parameters (same as part a)
params = struct();
params.E_L = -75e-3;           % Leak reversal potential in volts
params.V_th = -50e-3;          % Spike threshold in volts
params.V_reset = -80e-3;       % Reset potential in volts
params.R_m = 100e6;            % Membrane resistance in ohms
params.C_m = 100e-12;          % Membrane capacitance in farads
params.E_K = -80e-3;           % Potassium reversal potential in volts
params.Delta_G_SRA = 1e-9;     % Change in G_SRA at spike in Siemens
params.tau_SRA = 200e-3;       % Time constant for SRA decay in seconds

% Simulation settings for part b
T = 5;                          % Total time in seconds
dt = 1e-4;                      % Time step in seconds
t = 0:dt:T;                     % Time vector

% Define the range of applied currents from 0 pA to 500 pA
I_app_values = linspace(0, 500e-12, 20); % Applied current values in amperes

% Arrays to store the interspike intervals
first_ISIs = zeros(size(I_app_values));
steady_state_ISIs = zeros(size(I_app_values));
```

---

```

% Simulate for each current level
for idx = 1:length(I_app_values)
    I_app = I_app_values(idx) * ones(size(t)); % Constant current

    % Run the simulation
    [~, V, ~, ~] = simulate_LIF_with_adaptation(T, dt, I_app, params);

    % Detect spikes
    spikes = find(V(1:end-1) < params.V_th & V(2:end) >= params.V_th);
    spike_times = t(spikes);

    if length(spike_times) > 1
        % Calculate interspike intervals
        ISIs = diff(spike_times);
        first_ISIs(idx) = ISIs(1);
        steady_state_ISIs(idx) = mean(ISIs(end-4:end)); % Average the last
few ISIs for steady state
    else
        first_ISIs(idx) = NaN;
        steady_state_ISIs(idx) = NaN;
    end
end

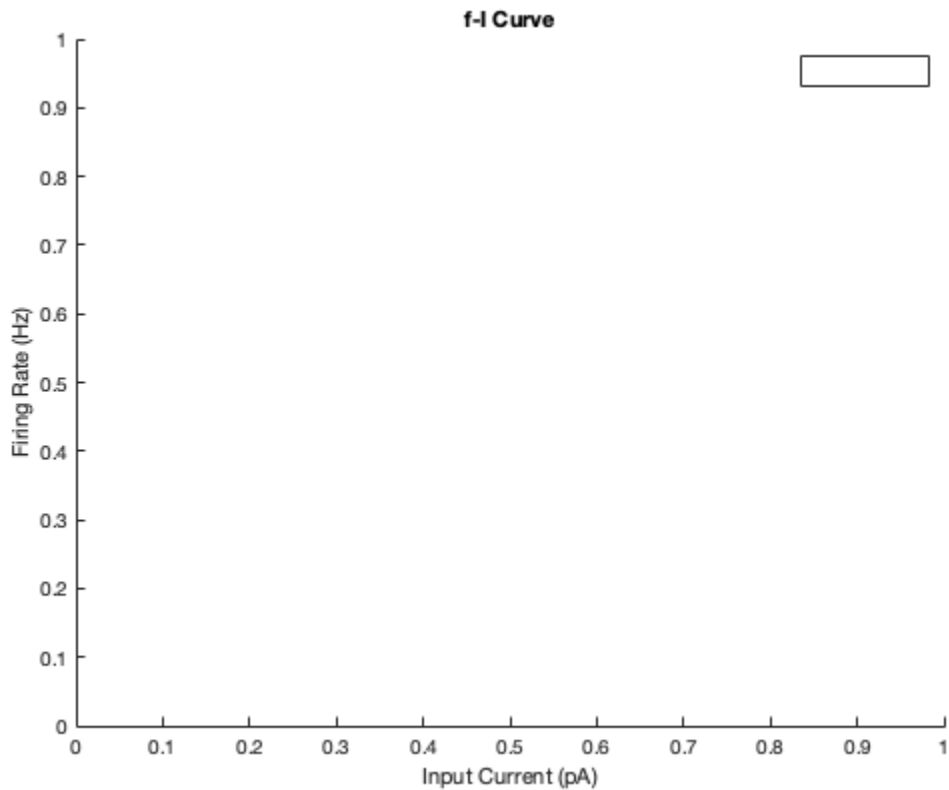
% Plotting the f-I curve
figure;
hold on;
% Check and plot only valid indices where ISI is not NaN and not Inf
valid_ss = ~isnan(1 ./ steady_state_ISIs) & ~isinf(1 ./ steady_state_ISIs);
valid_fi = ~isnan(1 ./ first_ISIs) & ~isinf(1 ./ first_ISIs);

plot(I_app_values(valid_ss) * 1e12, 1 ./ steady_state_ISIs(valid_ss), 'b-o',
'DisplayName', 'Steady-state ISI');
plot(I_app_values(valid_fi) * 1e12, 1 ./ first_ISIs(valid_fi), 'rx',
'DisplayName', 'First ISI');

xlabel('Input Current (pA)');
ylabel('Firing Rate (Hz)');
title('f-I Curve');
legend show;
hold off;

```

---



## Tutorial 2.3 Q2 Part a

```
function [V, I_SRA, spike_times] = simulate_AELIF(T, dt, I_app, params)
    % Initialize variables
    t = 0:dt:T;
    V = params.E_L * ones(1, length(t));
    I_SRA = zeros(1, length(t));
    spike_times = [];

    % Simulation loop
    for i = 2:length(t)
        % Membrane potential dynamics
        exp_term = params.Delta_th * exp((V(i-1) - params.V_th) /
params.Delta_th);
        dVdt = (params.G_L * (params.E_L - V(i-1) + exp_term) - I_SRA(i-1) +
I_app(i)) / params.C_m;
        V(i) = V(i-1) + dt * dVdt;

        % Adaptation current dynamics
        dISRA_dt = (params.a * (V(i-1) - params.E_L) - I_SRA(i-1)) /
params.tau_SRA;
        I_SRA(i) = I_SRA(i-1) + dt * dISRA_dt;

        % Spike condition
        if V(i) > params.V_max
```

---

```

        V(i) = params.V_reset;
        I_SRA(i) = I_SRA(i) + params.b;
        spike_times = [spike_times, i * dt]; % Record spike times
    end
end
end

% Define Parameters
params = struct();
params.E_L = -75e-3; % Resting membrane potential in volts
params.V_th = -50e-3; % Threshold potential in volts
params.V_reset = -80e-3; % Reset potential in volts
params.Delta_th = 2e-3; % Slope factor in volts
params.G_L = 10e-9; % Leak conductance in Siemens
params.C_m = 100e-12; % Membrane capacitance in Farads
params.a = 2e-9; % Subthreshold adaptation in Siemens
params.b = 0.02e-9; % Spike-triggered adaptation in Amperes
params.tau_SRA = 200e-3; % Adaptation time constant in seconds
params.V_max = 50e-3; % Spike cut-off potential in volts

% Simulation settings
T = 1.5; % Total simulation time in seconds
dt = 1e-4; % Time step in seconds
t = 0:dt:T; % Time vector
I_app = zeros(1, length(t)); % Initialize I_app for entire simulation
duration
I_app(t >= 0.5 & t <= 1.0) = 500e-12; % Current pulse from 0.5s to 1.0s

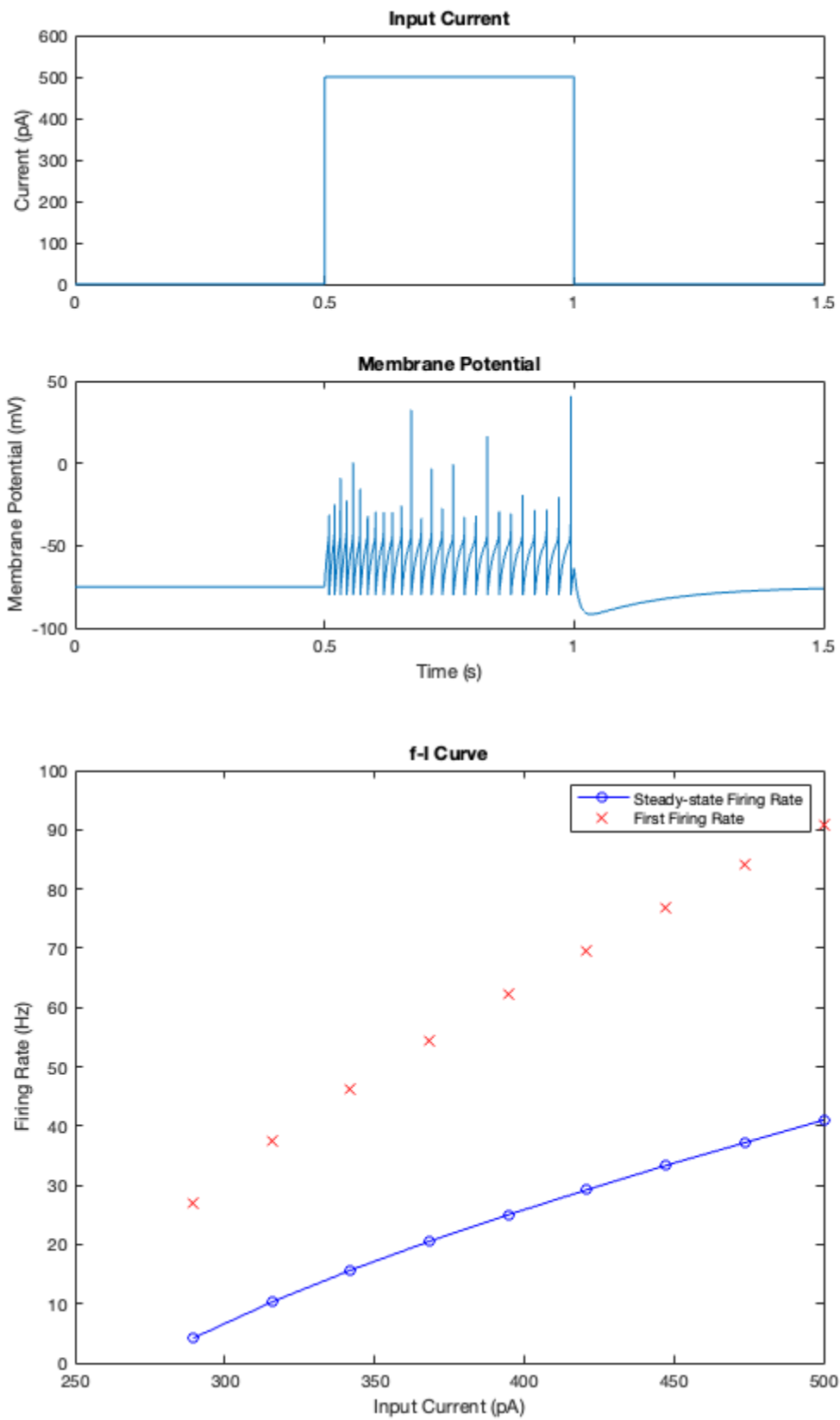
[V, I_SRA, ~] = simulate_AELIF(T, dt, I_app, params);

% Plotting
figure;
subplot(2,1,1);
plot(t, I_app * 1e12);
ylabel('Current (pA)');
title('Input Current');

subplot(2,1,2);
plot(t, V * 1e3);
ylabel('Membrane Potential (mV)');
xlabel('Time (s)');
title('Membrane Potential');

```

---



---

## Tutorial 2.3 Q2 Part b

```
% Simulation settings
T = 5;
dt = 1e-4;
t = 0:dt:T; % Ensure t is defined here or globally accessible
I_app_values = linspace(0, 500e-12, 20); % Applied current range

first_ISIs = [];
steady_state_ISIs = [];

for I_app_const = I_app_values
    I_app = I_app_const * ones(1, length(t)); % Make sure it spans the full
simulation duration
    [~, ~, spike_times] = simulate_AELIF(T, dt, I_app, params);

    if length(spike_times) > 1
        ISIs = diff(spike_times);
        first_ISIs(end+1) = ISIs(1);
        steady_state_ISIs(end+1) = mean(ISIs(end-4:end)); % Average last few
ISIs
    else
        first_ISIs(end+1) = NaN;
        steady_state_ISIs(end+1) = NaN;
    end
end

% Plotting f-I Curve
figure;
plot(I_app_values * 1e12, 1 ./ steady_state_ISIs, 'b-o', 'DisplayName',
'Steady-state Firing Rate');
hold on;
plot(I_app_values * 1e12, 1 ./ first_ISIs, 'rx', 'DisplayName', 'First Firing
Rate');
xlabel('Input Current (pA)');
ylabel('Firing Rate (Hz)');
title('f-I Curve');
legend;
hold off;
```

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